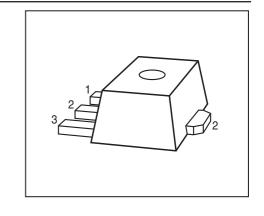


#### **PNP Silicon AF Transistors**

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCX54...BCX56 (NPN)
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101







Туре	Marking	P	Pin Configu	uration	Package
BCX51	AA	1=B	2=C	3=E	SOT89
BCX51-16	AD	1=B	2=C	3=E	SOT89
BCX52	AE	1=B	2=C	3=E	SOT89
BCX52-16	AM	1=B	2=C	3=E	SOT89
BCX53	AH	1=B	2=C	3=E	SOT89
BCX53-10	AK	1=B	2=C	3=E	SOT89
BCX53-16	AL	1=B	2=C	3=E	SOT89
		1	I		

1

K/W



**Maximum Ratings** 

Junction - soldering point1)

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$		V
BCX51		45	
BCX52		60	
BCX53		80	
Collector-base voltage	V <sub>CBO</sub>		
BCX51		45	
BCX52		60	
BCX53		100	
Emitter-base voltage	V <sub>EBO</sub>	5	
Collector current	I <sub>C</sub>	1	А
Peak collector current, t <sub>p</sub> ≤ 10 ms	I <sub>CM</sub>	1.5	
Base current	l <sub>B</sub>	100	mA
Peak base current	/ <sub>BM</sub>	200	
Total power dissipation	P <sub>tot</sub>	2	W
<i>T</i> <sub>S</sub> ≤ 120 °C			
Junction temperature	$T_{\rm j}$	150	°C
Storage temperature	$T_{ m stg}$	-65 150	
Thermal Resistance			
Parameter	Symbol	Value	Unit

 $R_{\mathrm{thJS}}$ 

≤ 15

 $<sup>^{1}</sup>$ For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



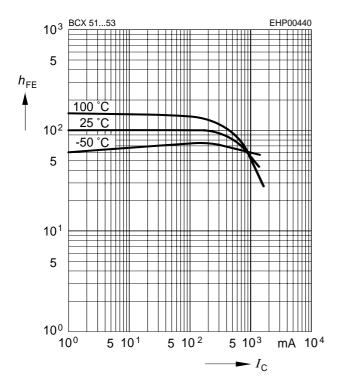
**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified **Symbol Values** Unit **Parameter** min. typ. max. **DC Characteristics**  $V_{(BR)CEO}$ ٧ Collector-emitter breakdown voltage  $I_{\rm C}$  = 10 mA,  $I_{\rm B}$  = 0 , BCX51 45  $I_{\rm C}$  = 10 mA,  $I_{\rm B}$  = 0 , BCX52 60 80  $I_{\rm C}$  = 10 mA,  $I_{\rm B}$  = 0 , BCX53 Collector-base breakdown voltage  $V_{(BR)CBO}$  $I_{\rm C} = 100 \, \mu \text{A}, I_{\rm F} = 0 \, , \, \text{BCX51}$ 45  $I_{\rm C} = 100 \, \mu \text{A}, I_{\rm F} = 0 \, , \, \text{BCX52}$ 60  $I_{\rm C} = 100 \, \mu \text{A}, I_{\rm F} = 0 \, , \, \text{BCX53}$ 100 Emitter-base breakdown voltage  $V_{(BR)EBO}$ 5  $I_{\rm E}$  = 10  $\mu$ A,  $I_{\rm C}$  = 0 Collector-base cutoff current μΑ *I*CBO  $V_{CB} = 30 \text{ V}, I_{F} = 0$ 0.1 20  $V_{CB} = 30 \text{ V}, I_{E} = 0 , T_{A} = 150 \text{ °C}$ DC current gain<sup>1)</sup>  $h_{\mathsf{FE}}$  $I_{\rm C} = 5 \text{ mA}, V_{\rm CF} = 2 \text{ V}$ 25  $I_{\rm C}$  = 150 mA,  $V_{\rm CF}$  = 2 V, BCX51...BCX53 40 250  $I_{\rm C}$  = 150 mA,  $V_{\rm CF}$  = 2 V, BCX53-10 63 100 160  $I_{\rm C}$  = 150 mA,  $V_{\rm CF}$  = 2 V, BCX51-16...BCX53-16 160 100 250  $I_{\rm C}$  = 500 mA,  $V_{\rm CF}$  = 2 V 25 Collector-emitter saturation voltage<sup>1)</sup>  $V_{\mathsf{CEsat}}$ V 0.5  $I_{\rm C}$  = 500 mA,  $I_{\rm B}$  = 50 mA Base-emitter voltage<sup>1)</sup> 1  $V_{\rm BE(ON)}$  $I_{\rm C}$  = 500 mA,  $V_{\rm CE}$  = 2 V **AC Characteristics** 125 MHz Transition frequency  $f_{\mathsf{T}}$  $I_{\rm C}$  = 50 mA,  $V_{\rm CE}$  = 10 V, f = 20 MHz

<sup>&</sup>lt;sup>1</sup>Pulse test: t < 300µs; D < 2%



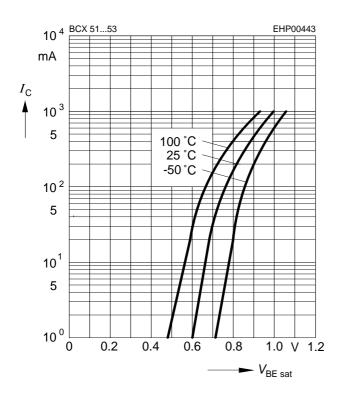
# **DC** current gain $h_{FE} = f(I_C)$

$$V_{CE} = 2 \text{ V}$$



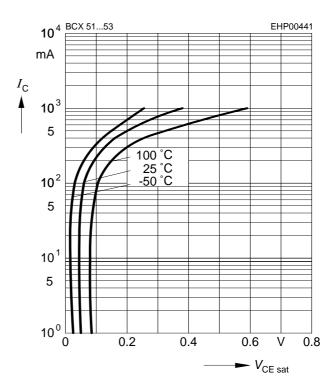
#### **Base-emitter saturation voltage**

$$I_{\rm C} = f(V_{\rm BEsat}), h_{\rm FE} = 10$$



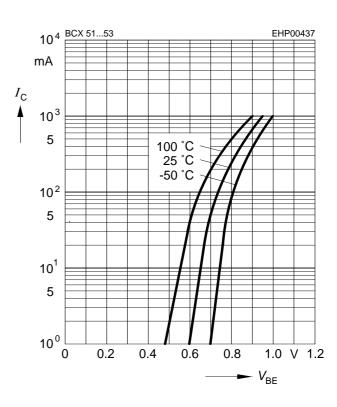
#### **Collector-emitter saturation voltage**

$$I_{\text{C}} = f(V_{\text{CEsat}}), h_{\text{FE}} = 10$$



# Collector current $I_{C} = f(V_{BE})$

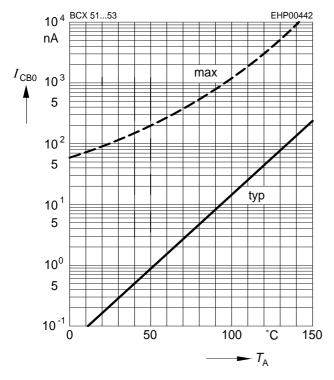
$$V_{CE} = 2V$$



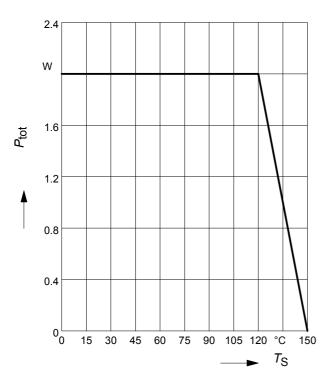


# Collector cutoff current $I_{CBO} = f(T_A)$

 $V_{\rm CBO}$  = 30 V

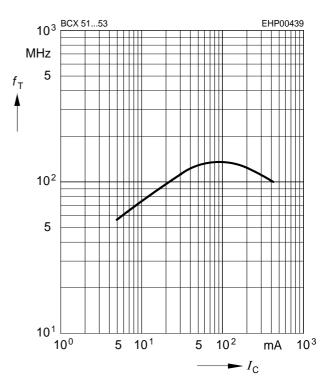


Total power dissipation  $P_{tot} = f(T_S)$ 

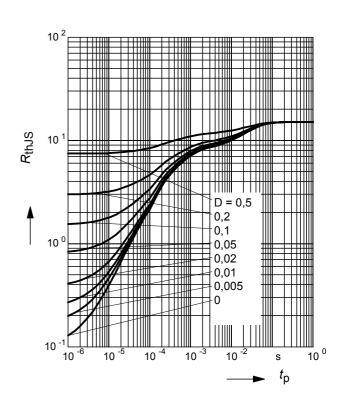


# Transition frequency $f_T = f(I_C)$

 $V_{CE}$  = 10 V



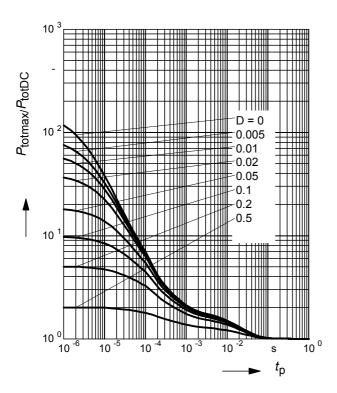
Permissible Pulse Load  $R_{thJS} = f(t_p)$ 





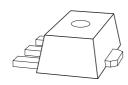
# **Permissible Pulse Load**

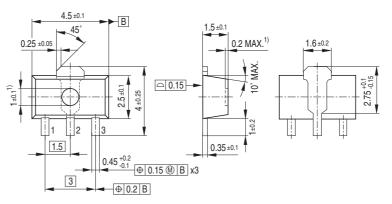
 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ 





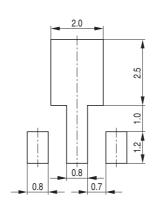
## Package Outline



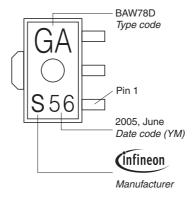


1) Ejector pin markings possible

#### Foot Print

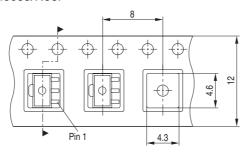


## Marking Layout (Example)



# Standard Packing

Reel ø180 mm = 1.000 Pieces/Reel Reel ø330 mm = 4.000 Pieces/Reel







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